



# PHOTOCOUPLER PS2841-4A, PS2841-4B

**WORLD'S SMALLEST CLASS, FOUR CHANNELS** –NEPOC Series–  
**12-PIN ULTRA SHRINK SOP PHOTOCOUPLER**

## DESCRIPTION

The PS2841-4A and PS2841-4B are optically coupled isolators containing GaAs light emitting diodes and NPN silicon phototransistors.

These products include four channels in a single package for high-density mounting applications.

The PS2841-4A and PS2841-4B are the world's smallest class of photocouplers and realize about 50% reduction in mounting area compared with the PS280x and PS281x Series.

## FEATURES

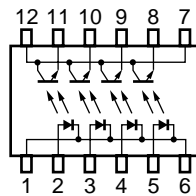
- Ultra small and thin package  
(12-pin ultra shrink SOP, Pin pitch 0.8 mm, 4.4 (L) × 5.6 (W) × 2.5 (H))
- Common lead PS2841-4A: cathode, collector common  
PS2841-4B: anode, collector common
- High current transfer ratio (CTR = 200% TYP. @ I<sub>f</sub> = 1mA)
- High isolation voltage (BV = 1 500 Vr.m.s.)
- Pb-Free product
- Ordering number of tape product:  
PS2841-4A-F3, F4: 2 500 pcs/reel  
PS2841-4B-F3, F4: 2 500 pcs/reel
- Safety standards
  - UL approved: File No. E72422

## APPLICATIONS

- Programmable logic controllers (PLCs)
- Input and output forfunction automation
- Hybrid IC

**PIN CONNECTIONS**  
(Top View)

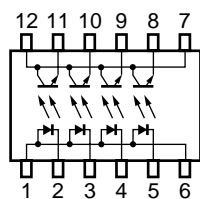
**PS2841-4A**



Channel	Anode	Cathode	Emitter	Collector
1 ch	2	1, 6 common	11	7, 12 common
2 ch	3	1, 6 common	10	7, 12 common
3 ch	4	1, 6 common	9	7, 12 common
4 ch	5	1, 6 common	8	7, 12 common

**PIN CONNECTIONS**  
(Top View)

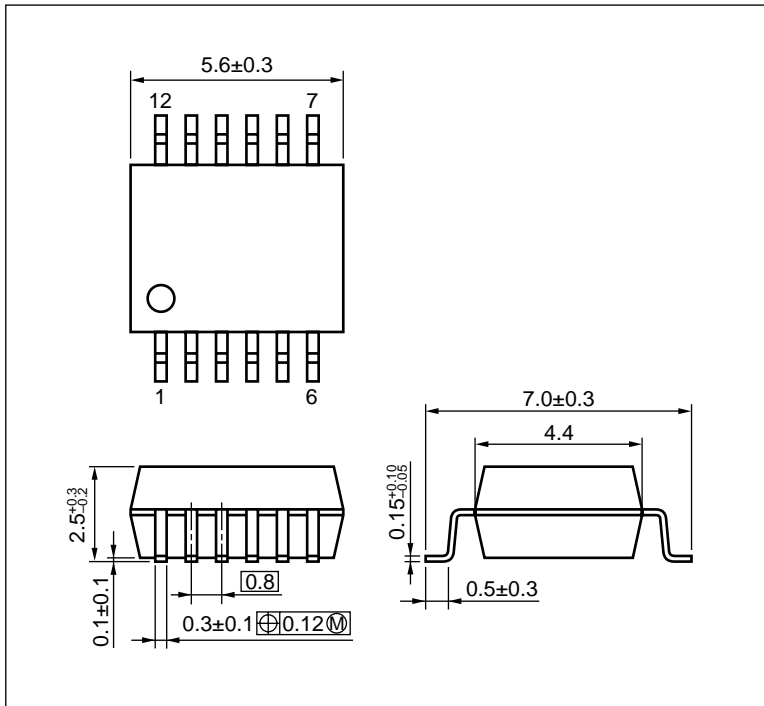
**PS2841-4B**



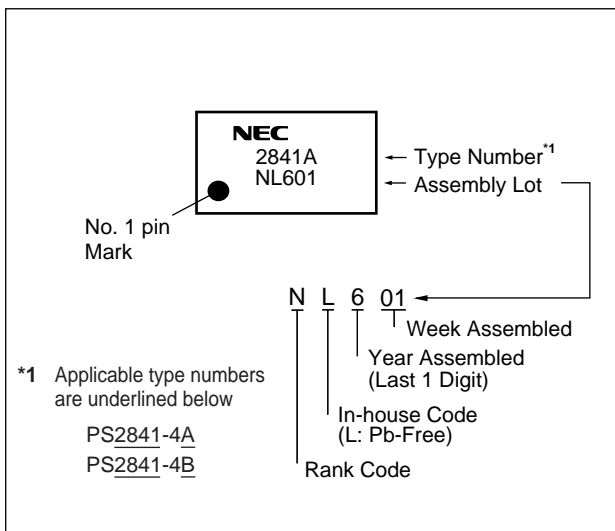
Channel	Anode	Cathode	Emitter	Collector
1 ch	1, 6 common	2	11	7, 12 common
2 ch	1, 6 common	3	10	7, 12 common
3 ch	1, 6 common	4	9	7, 12 common
4 ch	1, 6 common	5	8	7, 12 common

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

**PACKAGE DIMENSIONS (UNIT: mm)**



**<R> MARKING EXAMPLE**



<R> **ORDERING INFORMATION**

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number <sup>*1</sup>
PS2841-4A-F3	PS2841-4A-F3-A	Pb-Free	Embossed Tape 2 500 pcs/reel	Standard products (UL Approved)	PS2841-4A
PS2841-4A-F4	PS2841-4A-F4-A				
PS2841-4B-F3	PS2841-4B-F3-A				PS2841-4B
PS2841-4B-F4	PS2841-4B-F4-A				

\*1 For the application of the Safety Standard, following part number should be used.

**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C, unless otherwise specified)**

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	I <sub>F</sub>	20	mA/ch
	Reverse Voltage	V <sub>R</sub>	6	V
	Power Dissipation Derating	Δ I <sub>F</sub> /°C	0.2	mA /°C
	Peak Forward Current <sup>*1</sup>	I <sub>FP</sub>	0.5	A/ch
Transistor	Collector to Emitter Voltage	V <sub>CEO</sub>	70	V
	Emitter to Collector Voltage	V <sub>ECO</sub>	5	V
	Collector Current	I <sub>C</sub>	20	mA/ch
	Power Dissipation Derating	Δ P <sub>C</sub> /°C	0.4	mW/°C
	Power Dissipation	P <sub>C</sub>	40	mW/ch
Isolation Voltage <sup>*2</sup>		BV	1 500	Vr.m.s.
Operating Ambient Temperature		T <sub>A</sub>	-40 to +100	°C
Storage Temperature		T <sub>stg</sub>	-55 to +125	°C

\*1 PW = 100 μs, Duty Cycle = 1%

\*2 AC voltage for 1 minute at T<sub>A</sub> = 25°C, RH = 60% between input and output.  
Pins 1-6 shorted together, 7-12 shorted together.

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)**

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 1 mA	0.9	1.1	1.2	V
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 5 V			10	μA
	Terminal Capacitance	C <sub>T</sub>	V = 0 V, f = 1 MHz		15		pF
Transistor	Collector to Emitter Current	I <sub>CEO</sub>	I <sub>F</sub> = 0 mA, V <sub>CE</sub> = 24 V			100	nA
Coupled	Current Transfer Ratio (I <sub>C</sub> /I <sub>F</sub> )	CTR	I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 0.4 V	100	200	400	%
	Optical Leakage Current <sup>*1</sup> (1 to 2-ch, 2 to 3-ch, 3 to 4-ch)	I <sub>L</sub>	I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 24 V			100	nA
	Collector Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>F</sub> = 1 mA, I <sub>C</sub> = 0.2 mA		0.13	0.3	V
	Isolation Resistance	R <sub>I-O</sub>	V <sub>I-O</sub> = 1 kV <sub>DC</sub>	10 <sup>11</sup>			Ω
	Isolation Capacitance	C <sub>I-O</sub>	V = 0 V, f = 1 MHz		0.4		pF
	Turn-on Time <sup>*2</sup>	t <sub>on</sub>	V <sub>CC</sub> = 5 V, I <sub>F</sub> = 1 mA, R <sub>L</sub> = 5 kΩ		20		μs
	Turn-off Time <sup>*2</sup>	t <sub>off</sub>			110		

\*1 The optically induced leakage current is current which can be measured at transistor if LED = "ON" and LED = "OFF".

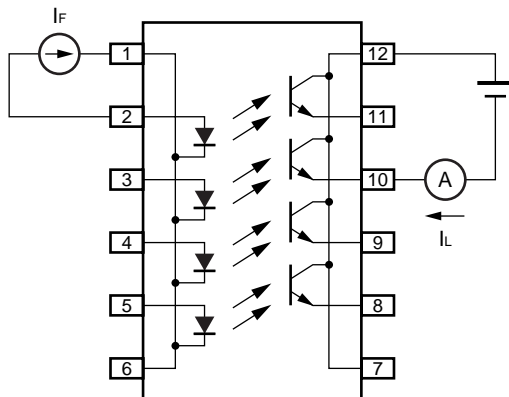
LED of channel 1 is switched to "ON".

At Tr-output of channel 2 a voltage is applied and one can measure a current between emitter and collector.

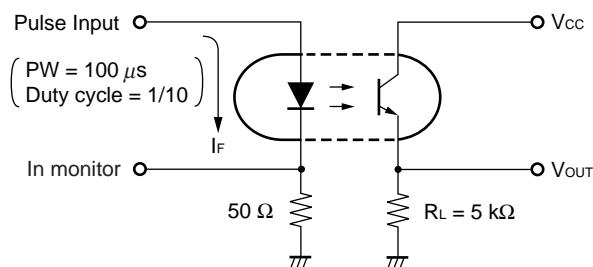
This is leakage current (at I<sub>F</sub> = 5 mA, V<sub>CEO</sub> = 24 V).

Measurement circuits for optical leakage current

E.g. : In the case of 1 to 2-ch (PS2841-4A)

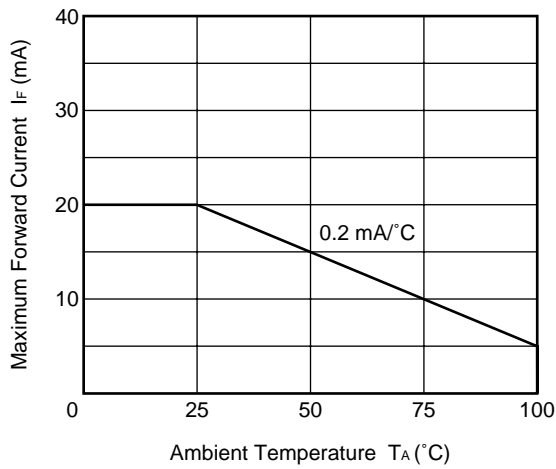


\*2 Test circuit for switching time

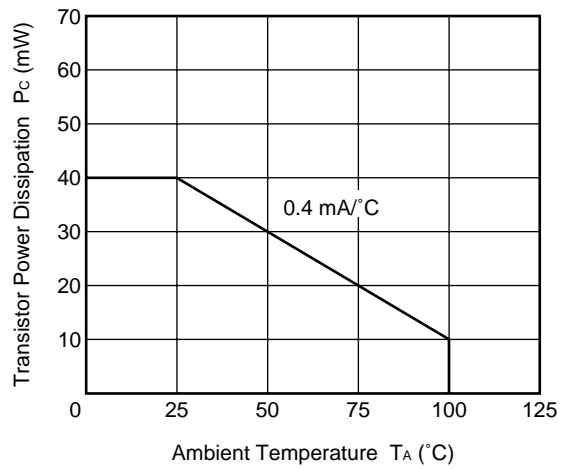


**TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, unless otherwise specified)**

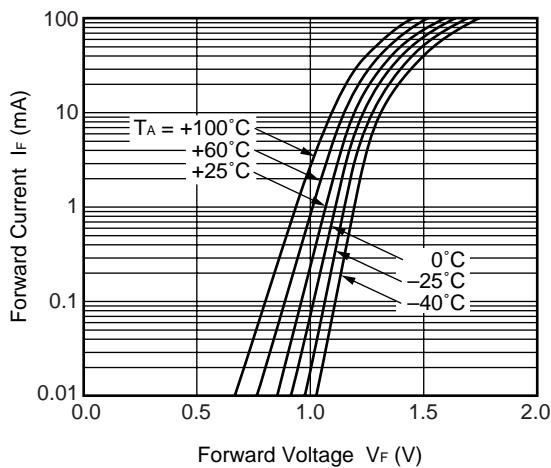
MAXIMUM FORWARD CURRENT vs. AMBIENT TEMPERATURE



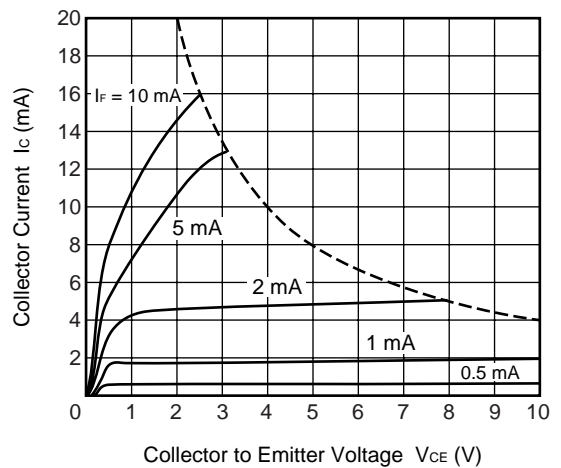
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



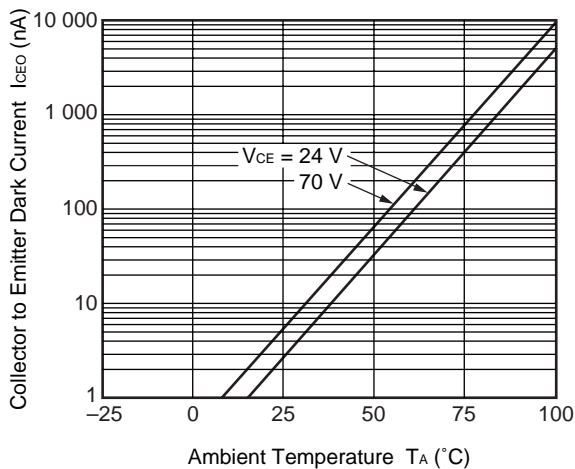
FORWARD CURRENT vs. FORWARD VOLTAGE



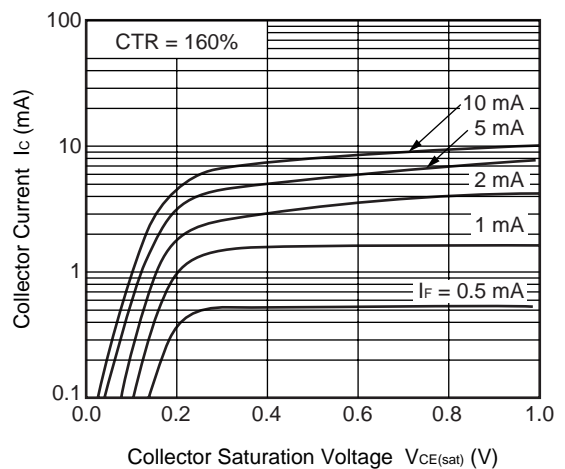
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE

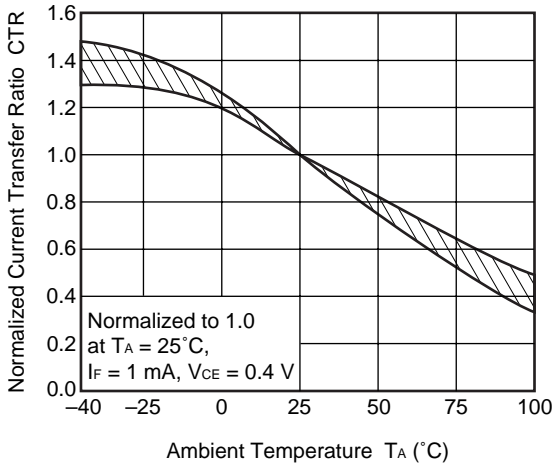


COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE

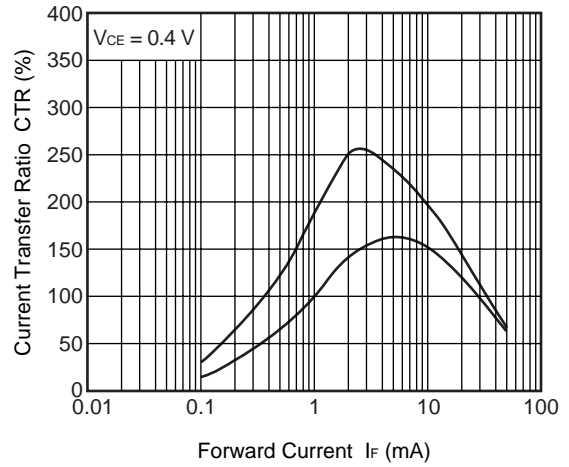


**Remark** The graphs indicate nominal characteristics.

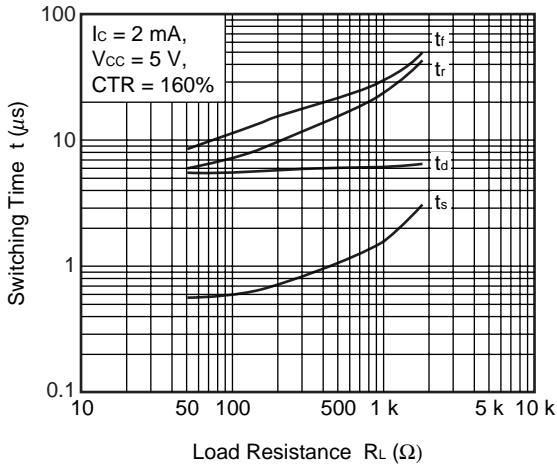
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



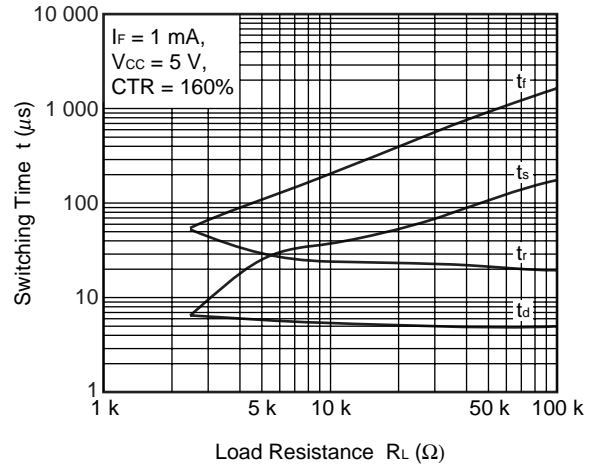
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



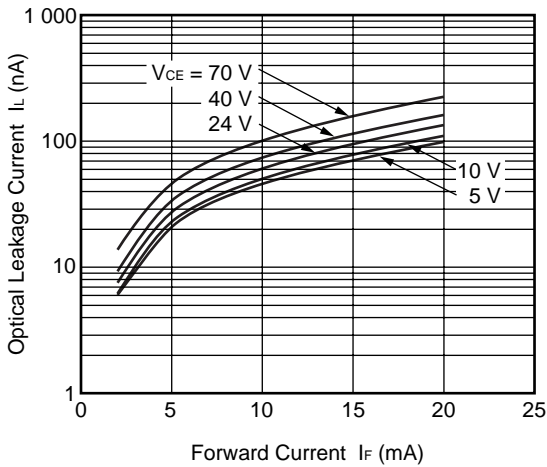
SWITCHING TIME vs. LOAD RESISTANCE



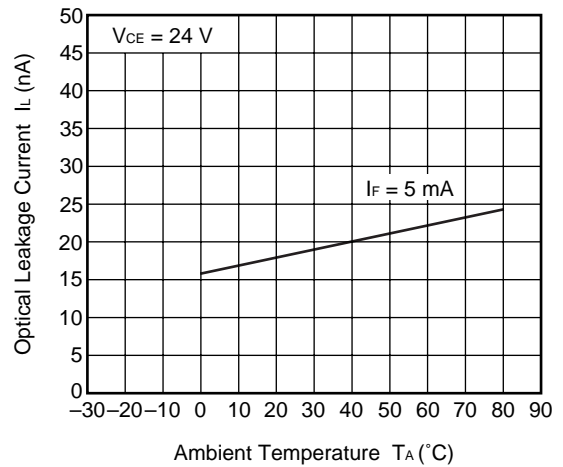
SWITCHING TIME vs. LOAD RESISTANCE



OPTICAL LEAKAGE CURRENT vs. FORWARD CURRENT



OPTICAL LEAKAGE CURRENT vs. AMBIENT TEMPERATURE



**Remark** The graphs indicate nominal characteristics.